



MCH3478

N-Channel Power MOSFET 30V, 2A, 165mΩ, Single MCPH3

ON Semiconductor®

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Features

- Low ON-resistance
- 1.8V drive
- Protection diode in
- Ultrahigh speed switching
- Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C

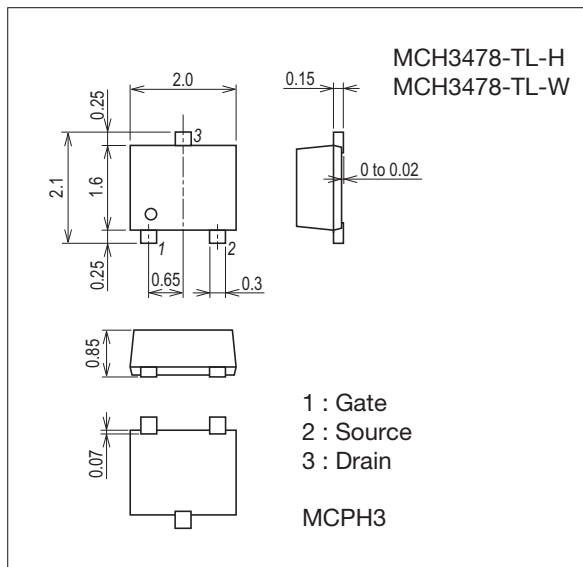
Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	V _{DSS}		30	V
Gate to Source Voltage	V _{GSS}		±12	V
Drain Current (DC)	I _D		2	A
Drain Current (PW≤10s)	I _D	Duty cycle≤1%	2.5	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	8	A
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (900mm ² ×0.8mm)	0.8	W
		When mounted on ceramic substrate (900mm ² ×0.8mm), PW=10s	1.2	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

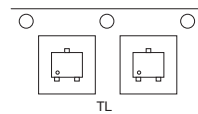
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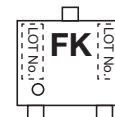
Product & Package Information

- Package : MCPH3
- JEITA, JEDEC : SC-70, SOT-323
- Minimum Packing Quantity : 3,000 pcs./reel

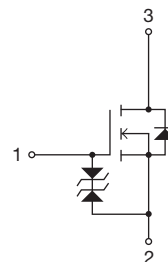
Packing Type : TL



Marking



Electrical Connection

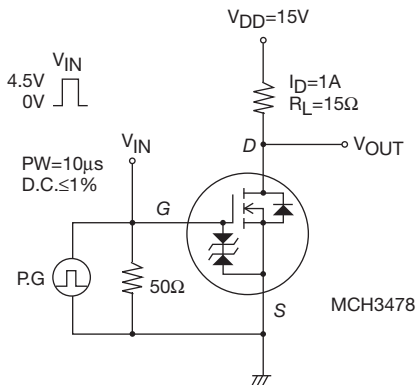


MCH3478

Electrical Characteristics at Ta=25°C

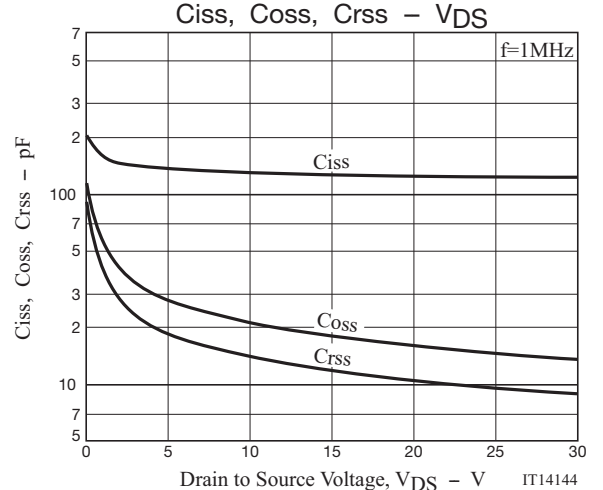
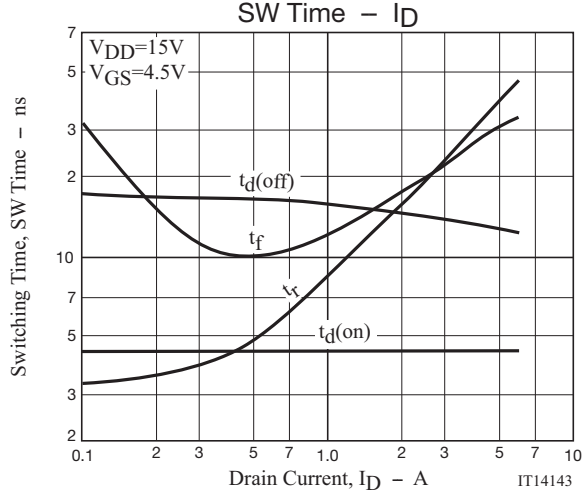
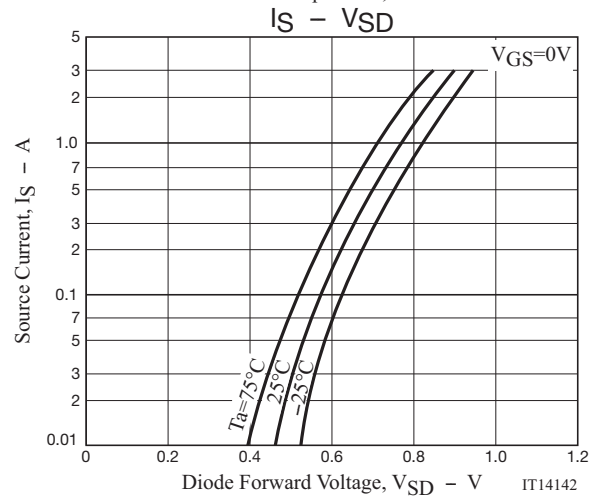
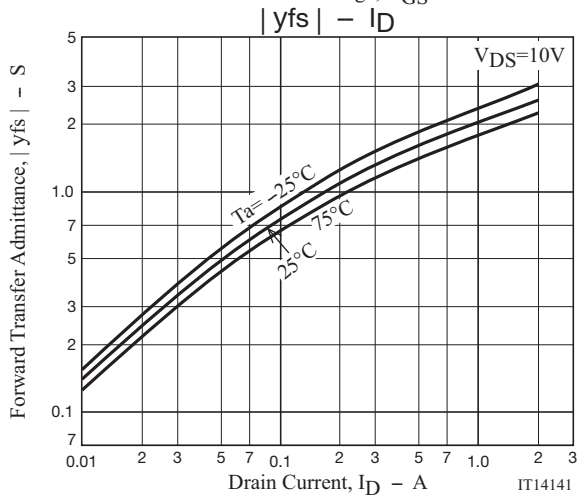
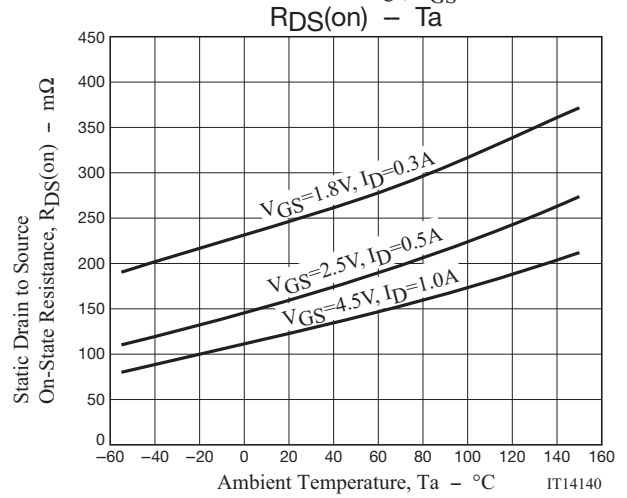
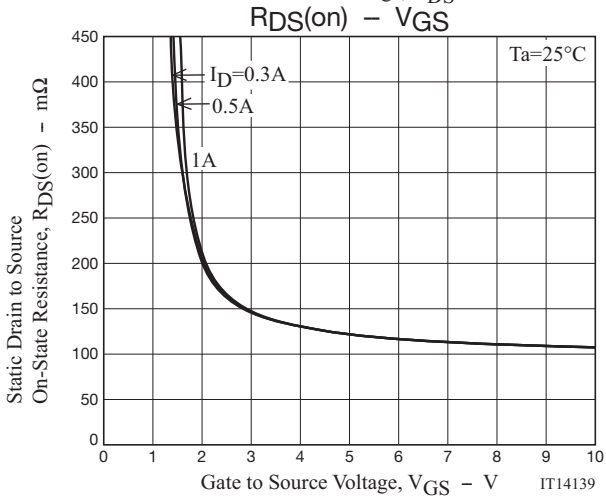
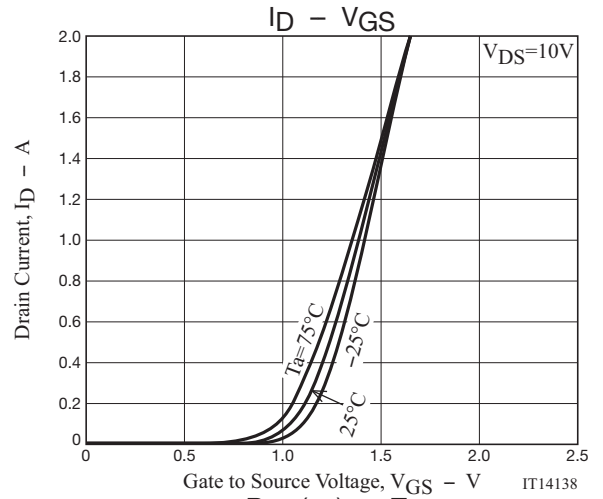
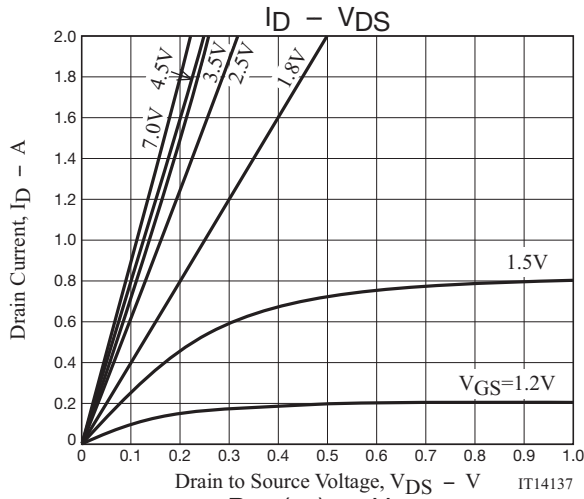
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0V			1	μA
Gate to Source Leakage Current	IGSS	VGS=±8V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	VDS=10V, ID=1A	1.2	2.0		S
Static Drain to Source On-State Resistance	RDS(on)1	ID=1A, VGS=4.5V		125	165	mΩ
	RDS(on)2	ID=0.5A, VGS=2.5V		165	235	mΩ
	RDS(on)3	ID=0.3A, VGS=1.8V		250	375	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		130		pF
Output Capacitance	Coss			21		pF
Reverse Transfer Capacitance	Crss			14		pF
Turn-ON Delay Time	td(on)		See specified Test Circuit.		4.4	
Rise Time	tr			8.7		ns
Turn-OFF Delay Time	td(off)			16		ns
Fall Time	tf			12		ns
Total Gate Charge	Qg	VDS=10V, VGS=4.5V, ID=2A			1.7	
Gate to Source Charge	Qgs			0.25		nC
Gate to Drain "Miller" Charge	Qgd			0.38		nC
Diode Forward Voltage	VSD	IS=2A, VGS=0V		0.85	1.2	V

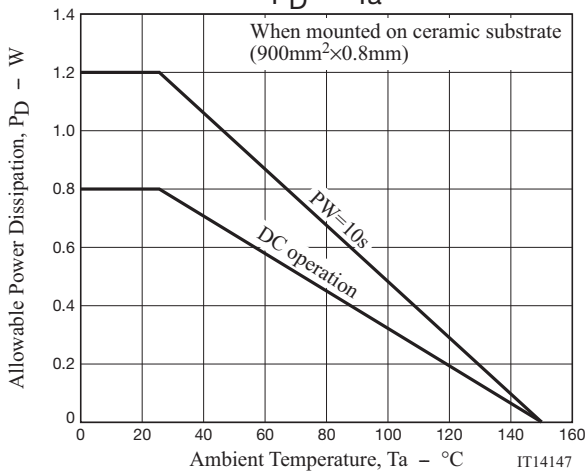
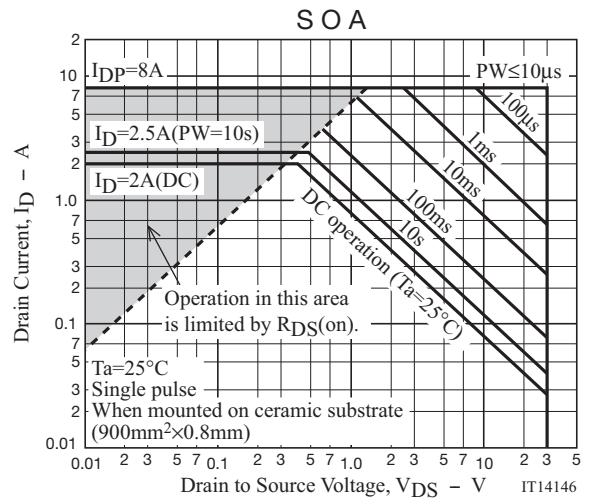
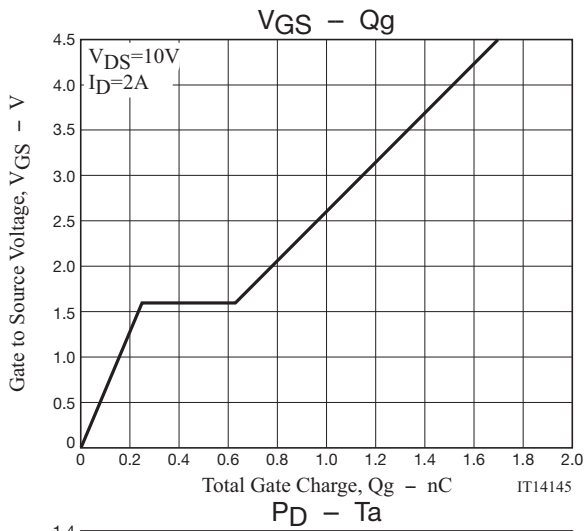
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
MCH3478-TL-H	MCPH3	3,000pcs./reel	Pb Free and Halogen Free
MCH3478-TL-W			

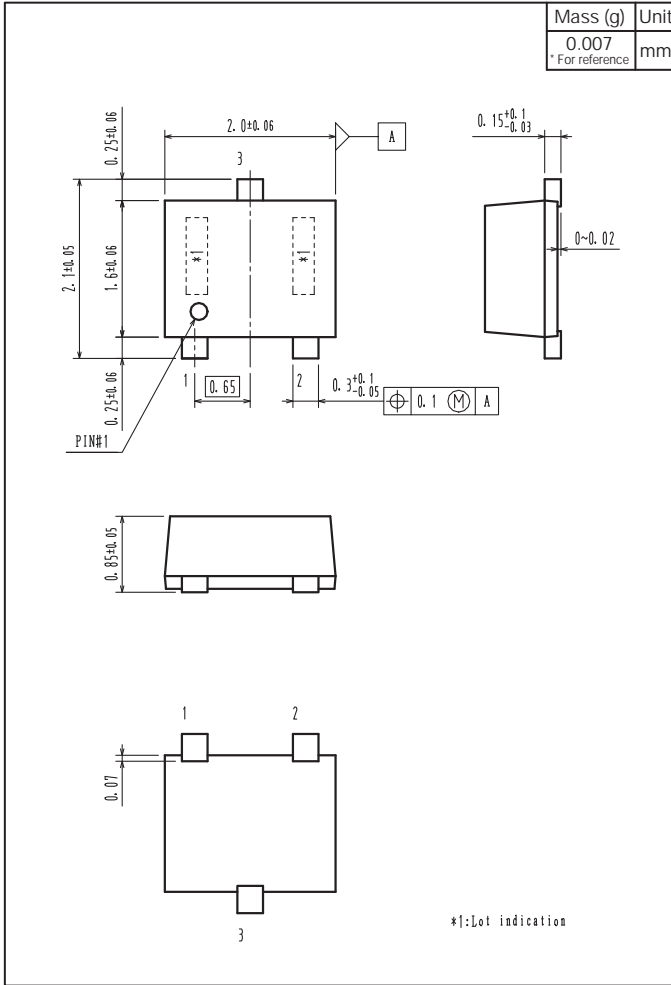




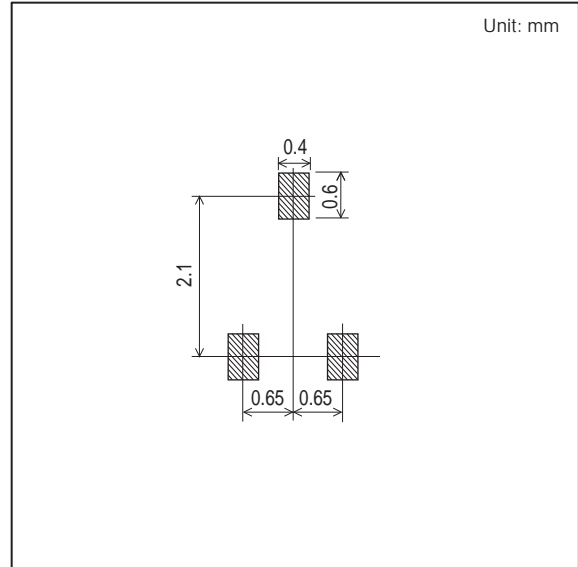
MCH3478

Outline Drawing

MCH3478-TL-H, MCH3478-TL-W



Land Pattern Example



Note on usage : Since the MCH3478 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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